



The Abdus Salam
International Centre for Theoretical Physics



2132-4

Winter College on Optics and Energy

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Photophysics for photovoltaics

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Winter College on Optics and Energy

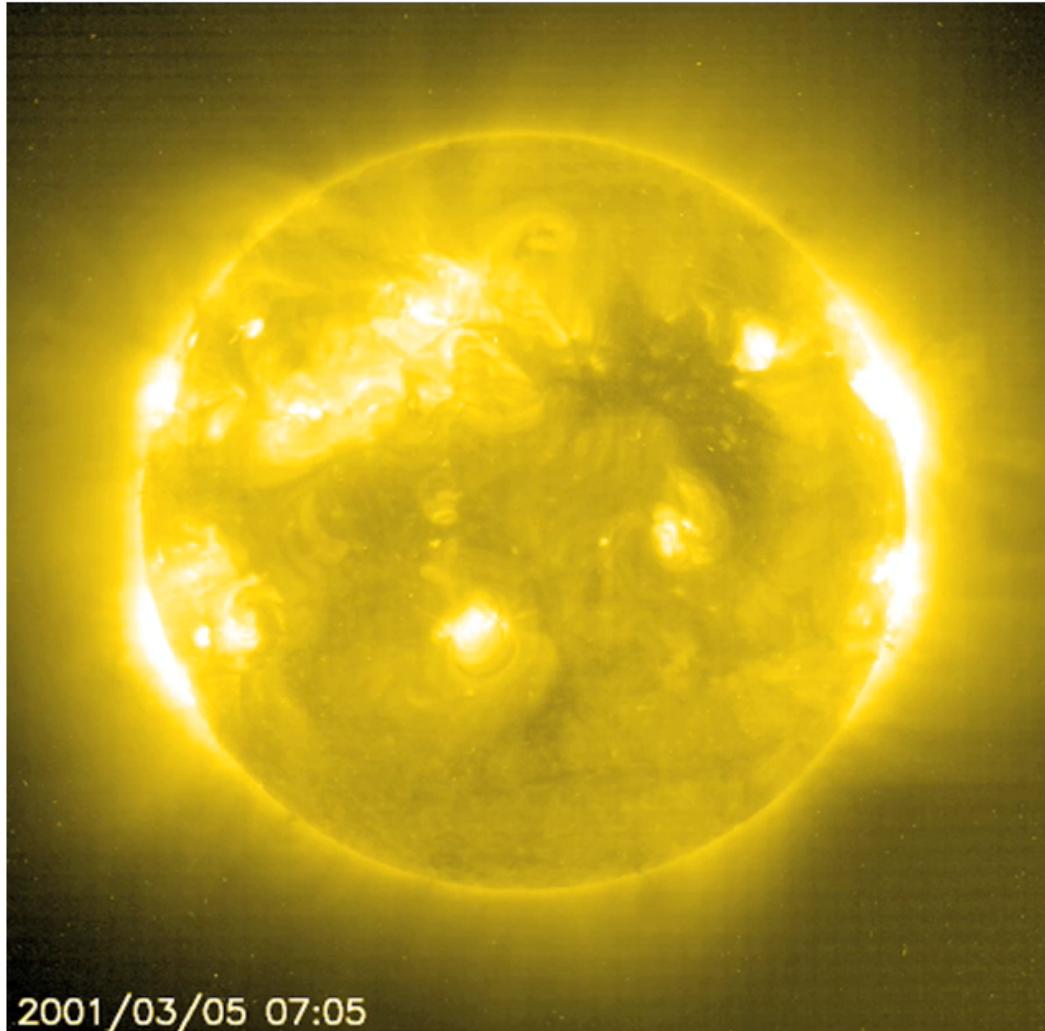
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Trieste, Italy

Safe, Cheap(?) Nuclear Energy



Core (15 million K),

Photosphere (visible surface, 5800 K)



movie

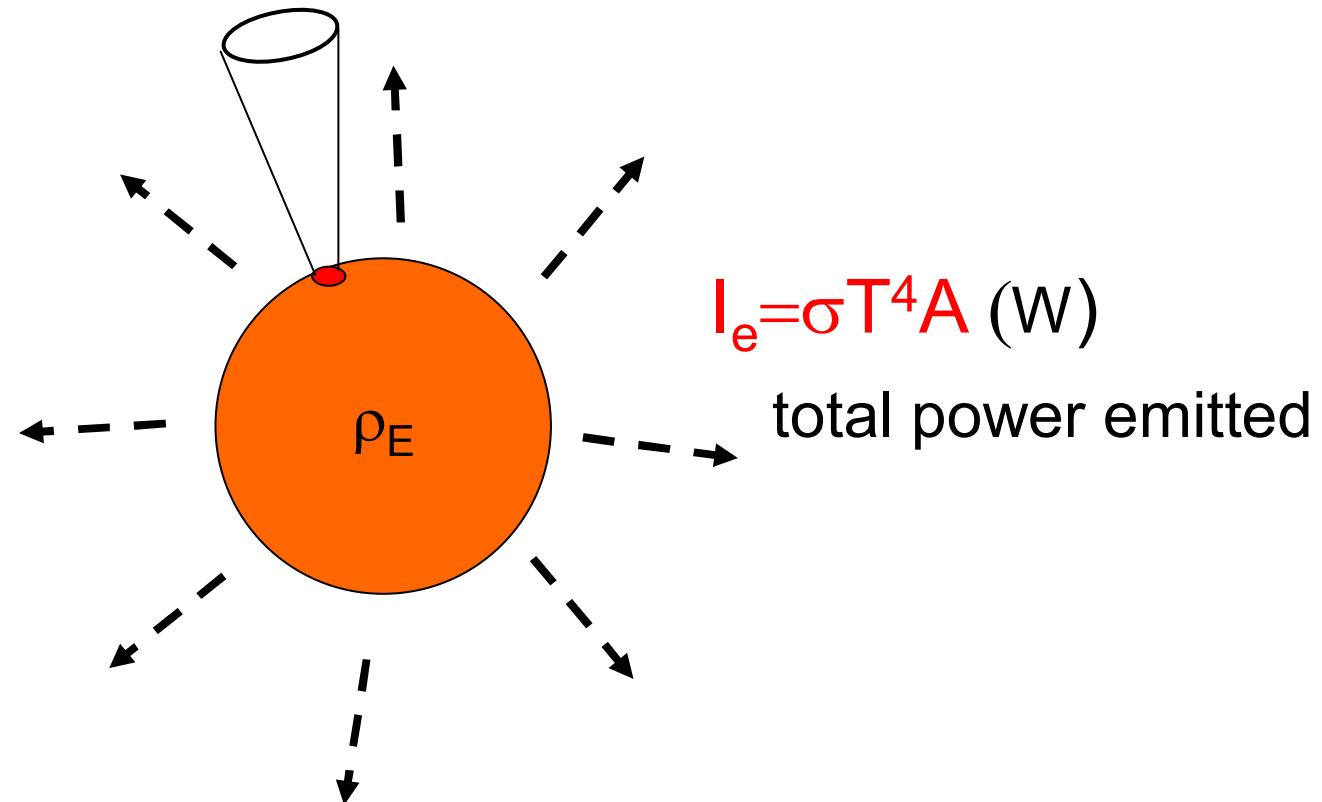
Is it enough?



Figure 5. The production of 20 TW of power, the world's mid-century projected demand, would require covering 0.16% of Earth's land (red squares) with 10%-efficient solar panels (courtesy of Prof. Nathan Lewis, Caltech, Pasadena).

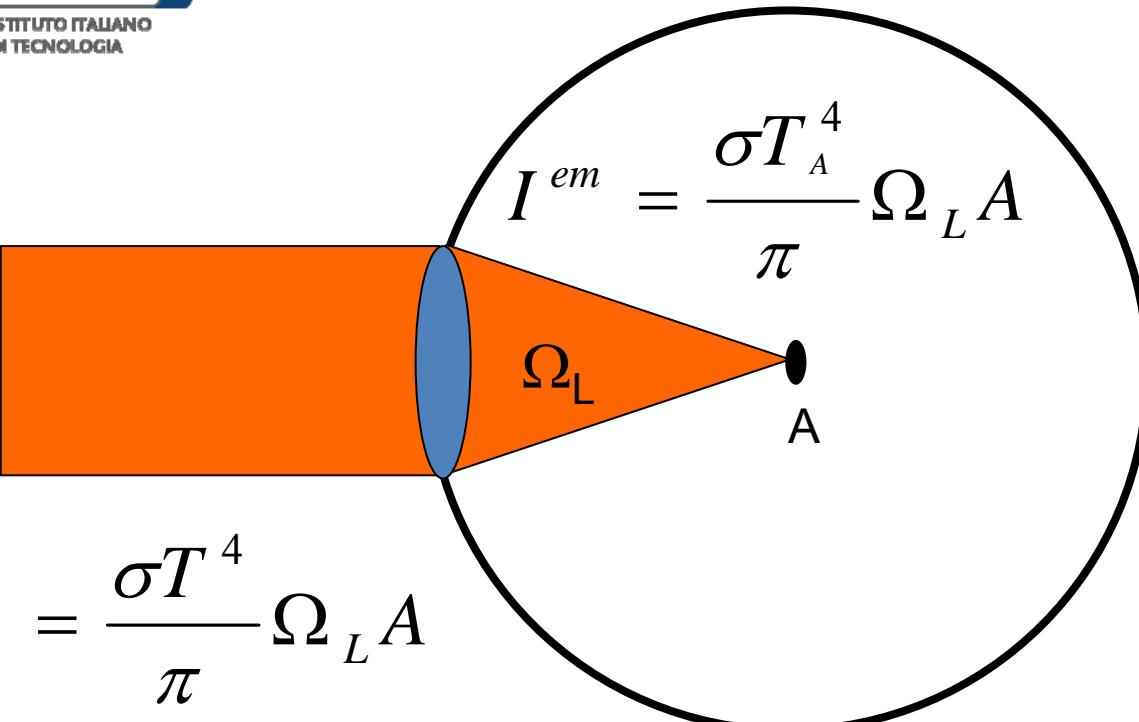
The sun as a black body

$$J_{e\Omega} = \sigma T^4 / \pi \text{ (W/Sr m}^2\text{)}$$



$$J_{e\Omega} = (\rho_E / 4\pi) \times c \text{ (W/Sr m}^2\text{)}$$

Thermodynamic limit



$$I^{em} = \frac{\sigma T_A^4}{\pi} \Omega_L A$$

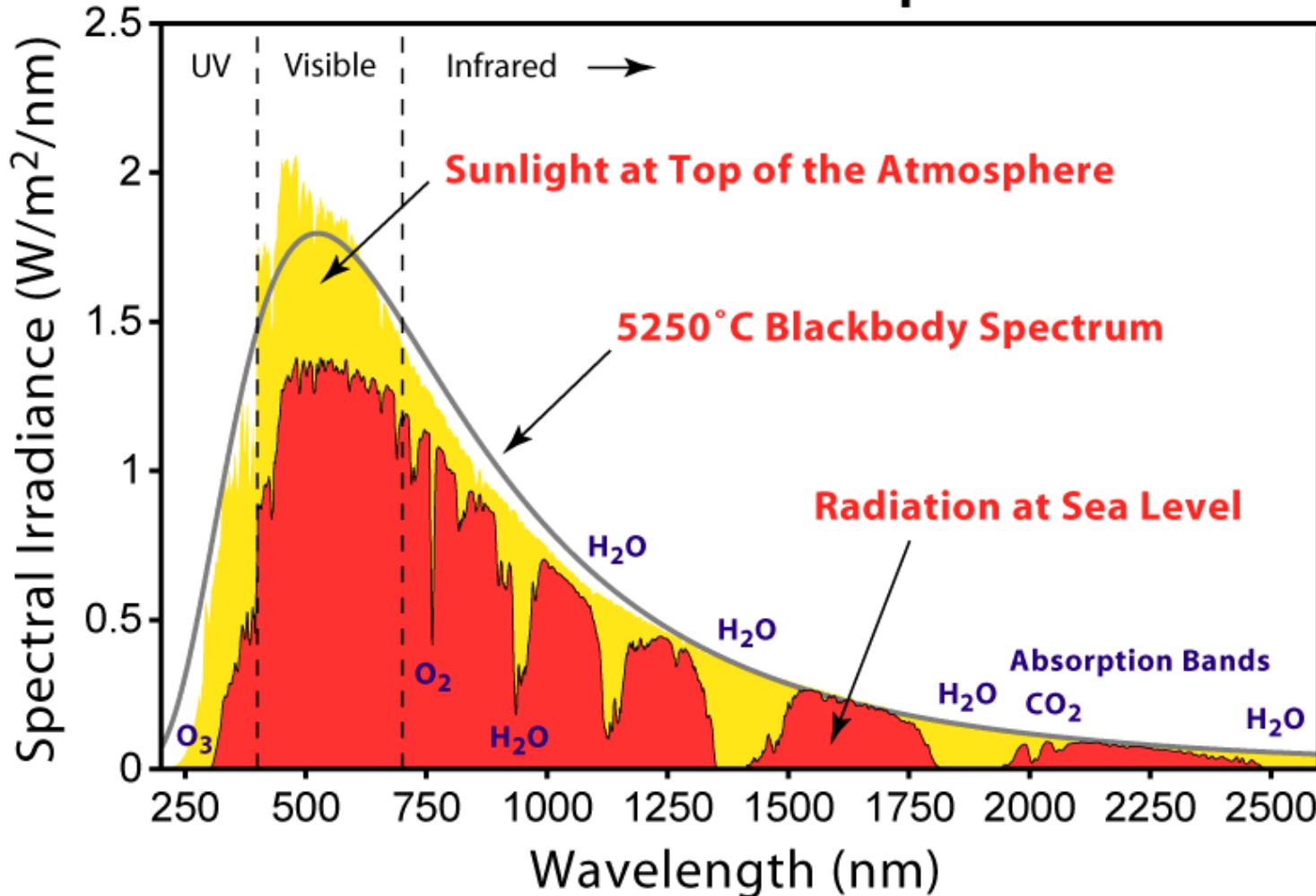
$$I^{sun} = \frac{\sigma T^4}{\pi} \Omega_L A$$

$$\eta_{abs} = \frac{I^{sun} - I^{em}}{I^{sun}} = 1 - \frac{T_A^4}{T_S^4}$$

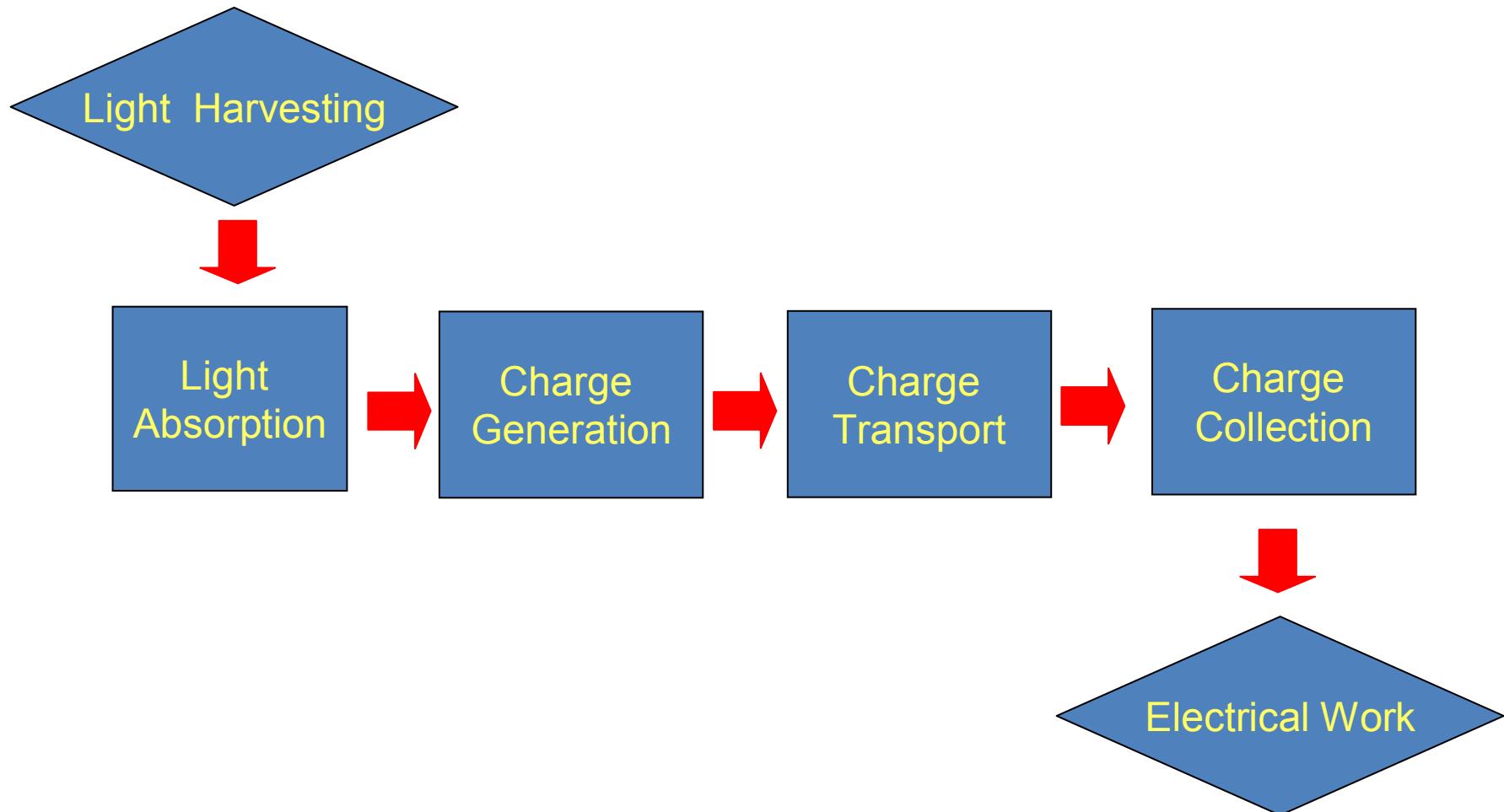
$$\eta_C = 1 - \frac{T_0}{T_A}$$

$$\eta_{TL} = \eta_{abs} \eta_C = \left(1 - \frac{T_A^4}{T_S^4}\right) \left(1 - \frac{T_0}{T_A}\right) = 85\%$$

Solar Radiation Spectrum

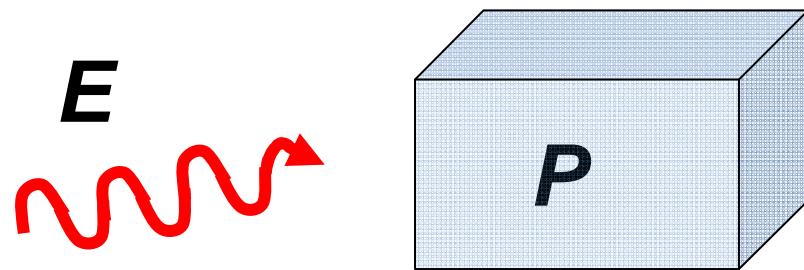


The PV lay-out



Absorption

The electro magnetic field interacting with a material can deposit energy at the characteristic frequency which defines the absorption spectrum.



$$\left\langle \frac{\text{power}}{\text{volume}} \right\rangle = \left\langle E_y(t) \frac{dP_y(t)}{dt} \right\rangle = \frac{1}{2} \operatorname{Re}[E(i\omega P)^*]$$

⟨ time - average ⟩

$$\tilde{A}_y(t) = \operatorname{Re} [A_y(t) e^{i\omega t}]$$

$$P = P(E)$$

$$P = P^{(1)} + P^{(2)} + P^{(3)} +$$

$$P^{(1)}(\omega) = \epsilon_0 \chi^{(1)}(\omega) E(\omega)$$

$$\chi^{(1)}(\omega) = \text{Re } \chi^{(1)}(\omega) - i \text{Im } \chi^{(1)}(\omega)$$

$$\left\langle \frac{\text{power}}{\text{volume}} \right\rangle = \frac{1}{2} \omega \epsilon_0 \text{Im } \chi^{(1)} |E|^2$$

The Lambert-Beer approximation

$$I_t = I_0 e^{-\alpha(\omega)z}$$

$$T = I_t / I_o$$

$$A = -\log_{10} T$$

$$\frac{dI}{dz} = - \left\langle \frac{\text{power dissipated}}{\text{unit volume}} \right\rangle = -\frac{1}{2} \omega \epsilon_0 \operatorname{Im} \chi^{(1)} |E|^2$$

$$I = \frac{c \epsilon}{2n} |E|^2$$

$$\frac{\epsilon}{\epsilon_0} = n^2$$

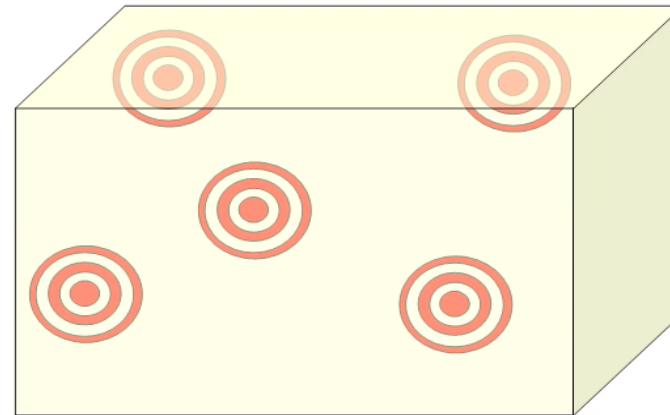
$$\alpha = \frac{\omega}{cn} \operatorname{Im} \chi^{(1)} = \underline{\sigma(\omega) \Delta N}$$

Cross-section

POPULATION

The concept of cross-section

$$[\sigma] = \text{cm}^2$$



F = number of photons per unit area and unit time

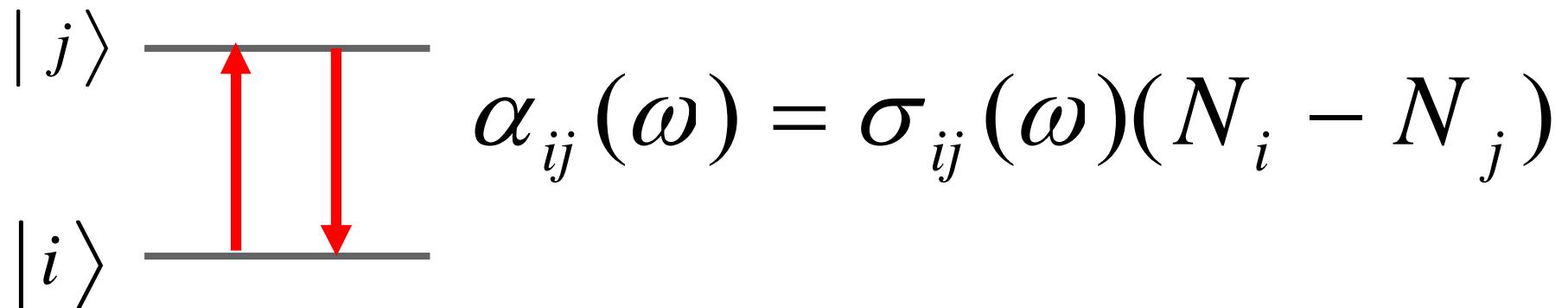
N = number of target per unit volume

σN = effective total area per unit volume [L^{-1}]

σNF = number of transition per unit time, i.e. transition rate

movie

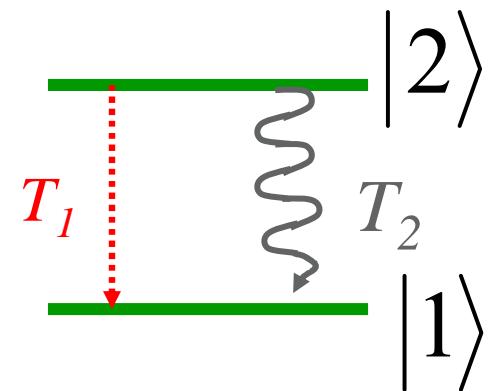
Absorption and population



$$\alpha = \sum_{i,j} \sigma_{ij}(\omega)(N_i - N_j)$$

Cross-section for the two level model

$$\sigma(\omega) = \frac{\omega}{2c} \frac{\mu^2}{\epsilon_0 \hbar n} g(\omega)$$



$$g(\omega) = \frac{\Delta\omega}{(\omega - \omega_0)^2 + \left(\frac{\Delta\omega}{2}\right)^2}$$

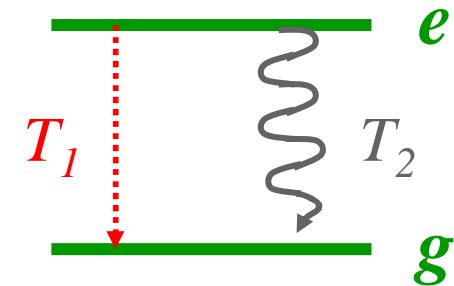
$$\Delta\omega = \frac{2}{T_2}$$

$$\mu_{12} = \langle 2 | \tilde{\mu} | 1 \rangle = \mu_{21}^*$$

Optical Bloch Equation

$$\Delta n = N_e - N_g$$

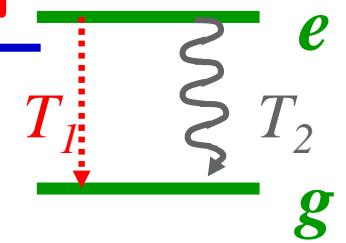
$$P = N \mu_{ge}$$



$$\frac{\partial \Delta n}{\partial t} + \frac{\Delta n - \Delta n_0}{T_1} = -\frac{2}{\hbar\omega} \bar{E} \cdot \frac{\partial \bar{P}}{\partial t}$$

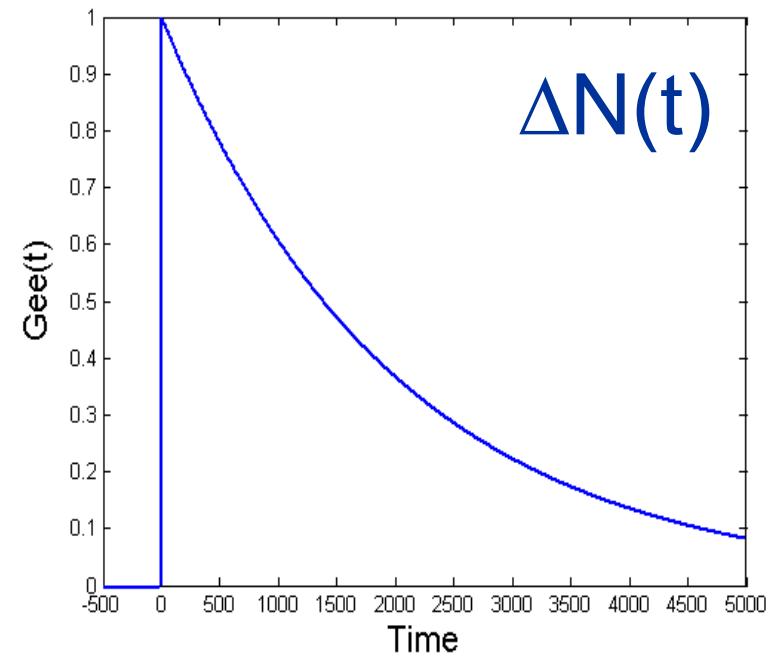
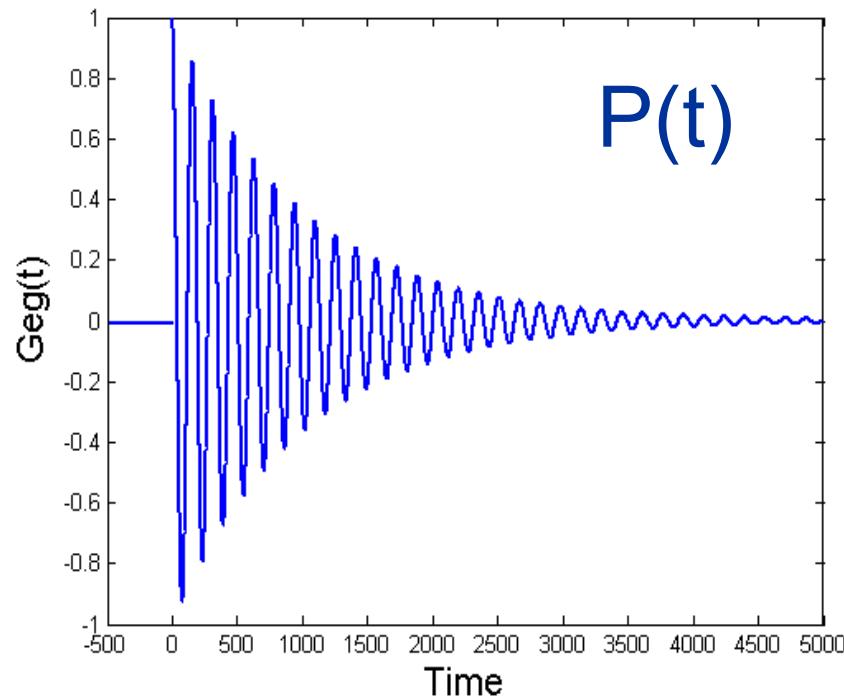
$$\frac{\partial^2 \bar{P}}{\partial t^2} + \frac{2}{T_2} \frac{\partial \bar{P}}{\partial t} + \omega^2 \bar{P} = \frac{2\omega |\mu|^2}{3\hbar} \Delta n \bar{E}$$

Impulsive response function of the material



$$G_{eg} = \frac{i}{\hbar} \vartheta(t) \exp(-i\omega_{eg}t - t/T_2)$$

$$G_{ee} = \frac{i}{\hbar} \vartheta(t) \exp(-t/T_1)$$



Adibatic Approximation and Frank-Condon Overlap

$$m_e/M_N \ll 1 \text{ or } \Delta E_e/\Delta E_N \gg 1 \quad \rightarrow \quad \Psi = \psi(q, Q)\phi(Q)$$

$$\tilde{\mu} = \langle \psi_e(q, Q) \phi_{en}(Q) | \mu_{eg}(q) | \psi_g(q, Q) \phi_{gl}(Q) \rangle$$

Electronic contribution

$$\langle \psi_e(q, Q) | \mu_{eg}(q) | \psi_g(q, Q) \rangle = \tilde{\mu}_{eg} + \dot{\mu}_{eg} Q + \dots$$

Condon approximation:

$$\alpha \propto \left| \langle \psi_e(q, Q) | \mu_{eg}(q) | \psi_g(q, Q) \rangle \langle \phi_{en}(Q) \phi_{gl}(Q) \rangle \right|^2$$

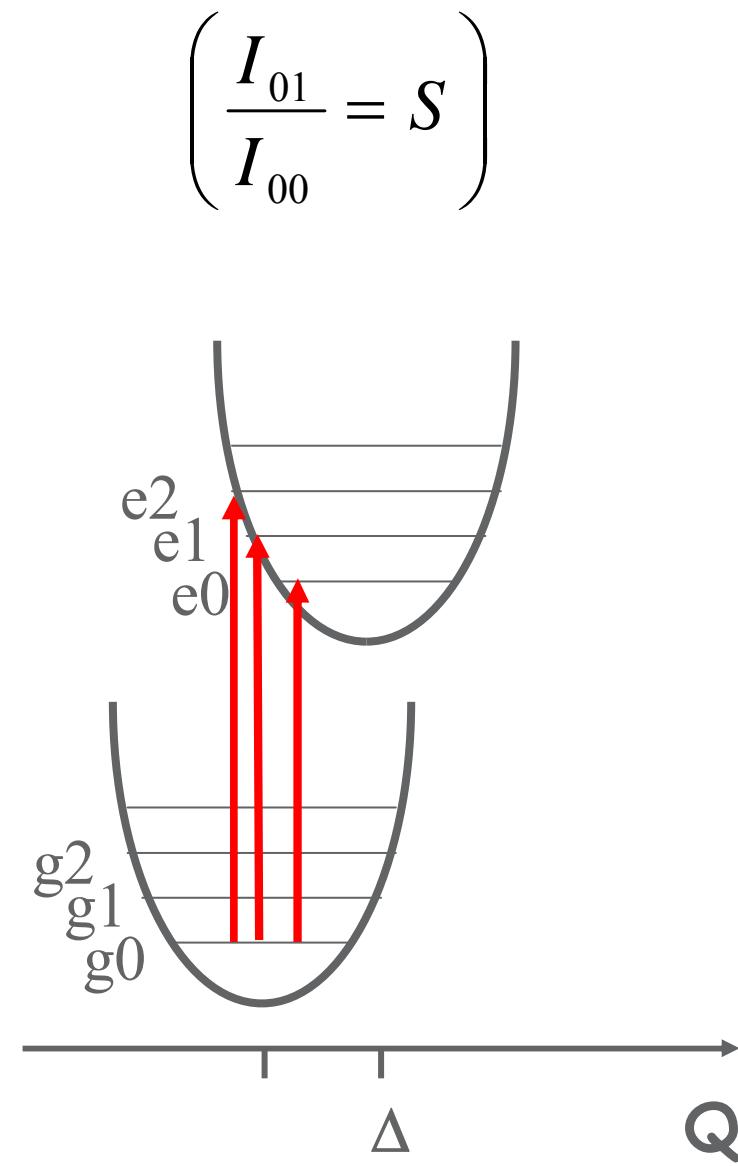
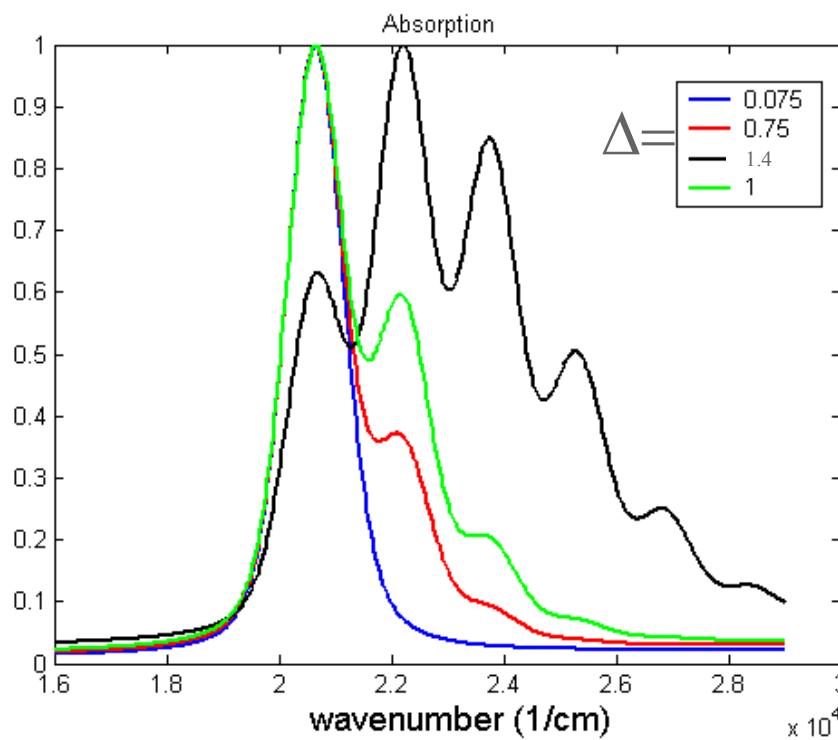
$$\alpha \propto |\tilde{\mu}_{eg}|^2 F C(n, l) g(\omega - \omega_{en/gl})$$

FC: Displaced Harmonic Oscillators (T=0)

$$I_{n0} \propto |\tilde{\mu}_{eg}|^2 \frac{e^{-S} S^n}{n!} g(\omega - \omega_{en/g_0})$$

FC

$$S = \frac{\Delta^2}{2} \quad \Delta = \left(\frac{m \omega}{\hbar} \right)^{1/2} \delta Q$$



Molecular absorption cross-section

Adiabatic approximation $\Psi = \psi(q, Q)\phi(Q)$

Dipole allowed transition $\mu = \langle \psi_e | \hat{\mu} | \psi_g \rangle \neq 0$

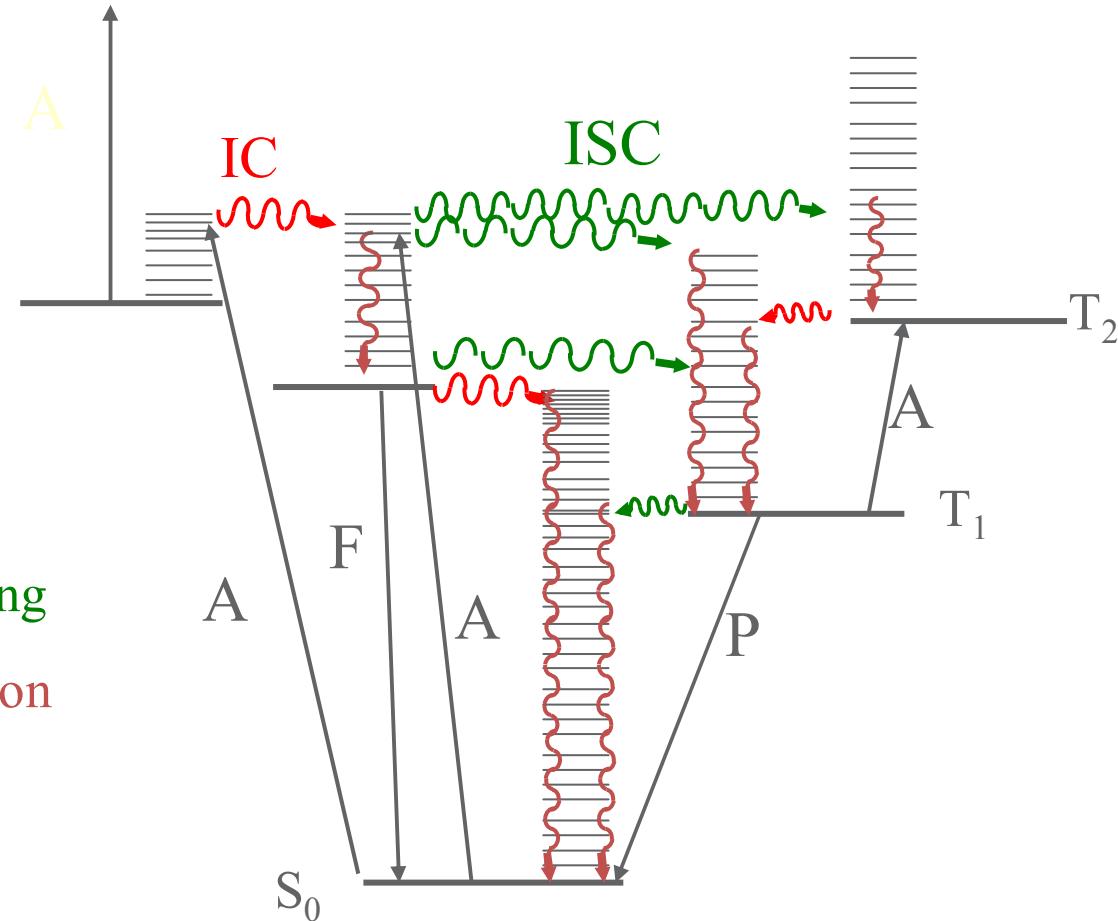
Condon approximation $\mu(Q) = \mu_0$

$$\sigma_A = \frac{\omega}{c} \frac{\mu_0^2}{2\epsilon_0} \sum_i B_i \sum_f \frac{1}{\pi} \frac{\left| \langle \phi_f | \phi_i \rangle \right|^2 \Gamma}{(E_F - E_i - \hbar\omega)^2 + \Gamma^2}$$



$B_i \equiv$ Boltzman factor

Jablonski diagram unimolecular photophysical processes



$IC \equiv$ Internal Conversion

$ISC \equiv$ Inter System Crossing

$VR \equiv$ Vibrational Relaxation

$A \equiv$ Absorption

$F \equiv$ Fluorescence

$P \equiv$ Phosphorescence

Dynamics comes in

For a given process "i" a monomolecular rate k_i is defined, $k_i = 1/\tau_i$ (s⁻¹)

The total rate is $k_T = k_0 + \sum_i k_i$, efficiency $\eta_i = \frac{k_i}{k_T}$

$$k_{VR} \approx 10^{12}-10^{13} \text{ s}^{-1}$$

$$k_{IC} \approx 10^{12}-10^{14} \text{ s}^{-1} (S_n \rightarrow S_1)$$

$$k_{IC} \approx 10^8-10^{10} \text{ s}^{-1} (S_1 \rightarrow S_0)$$

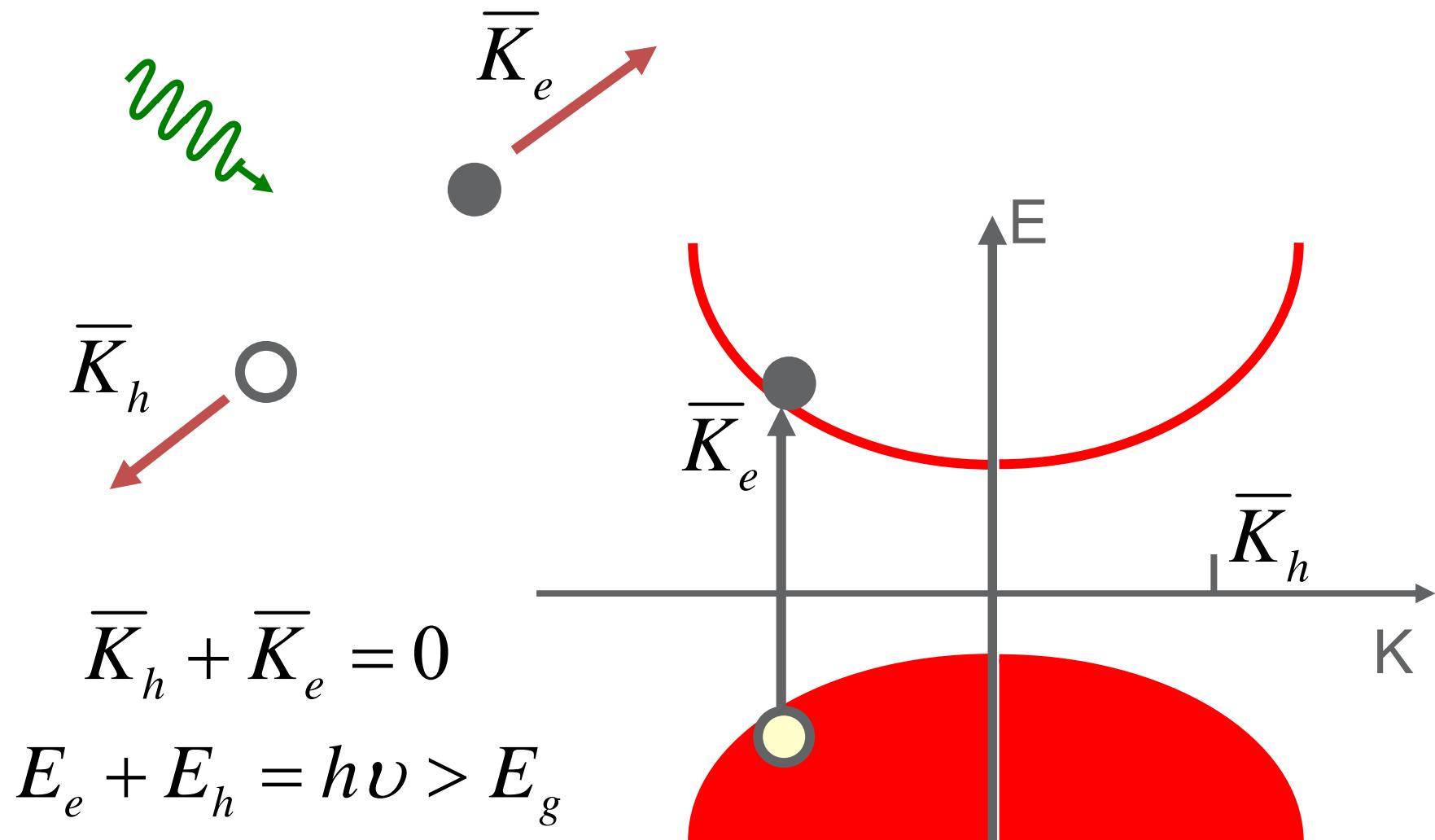
$$k_{ST} \approx 10^6-10^{11} \text{ s}^{-1} (S_1 \rightarrow T_1)$$

$$k_{TS} \approx 10^4-10^7 \text{ s}^{-1} (T_1 \rightarrow S_0)$$



CHARGE PHOTO GENERATION (CPG)

Band-like semiconductor: CPG



Charge photo-generation

$$\eta = \frac{n.(e - h)}{n. photons}$$

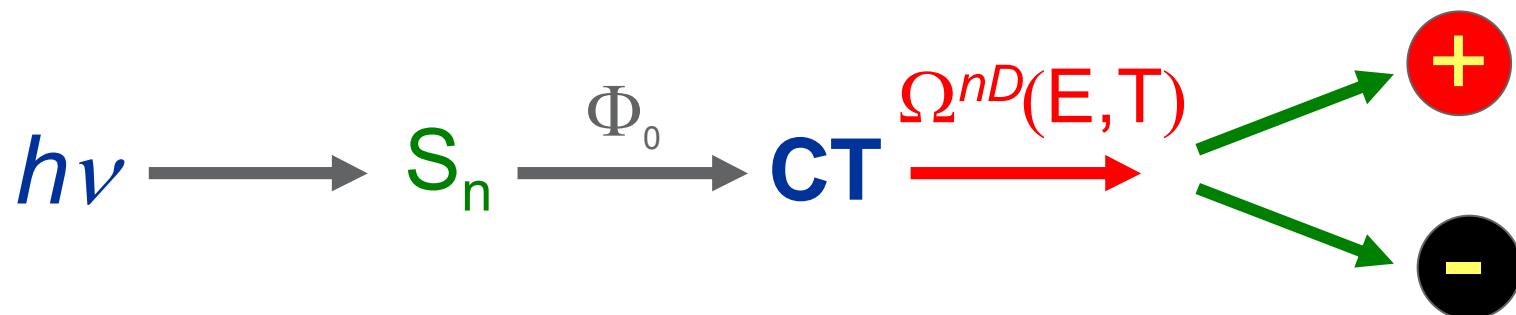
CB-VB
Xtal, Inorganic

$$\eta \approx 1$$



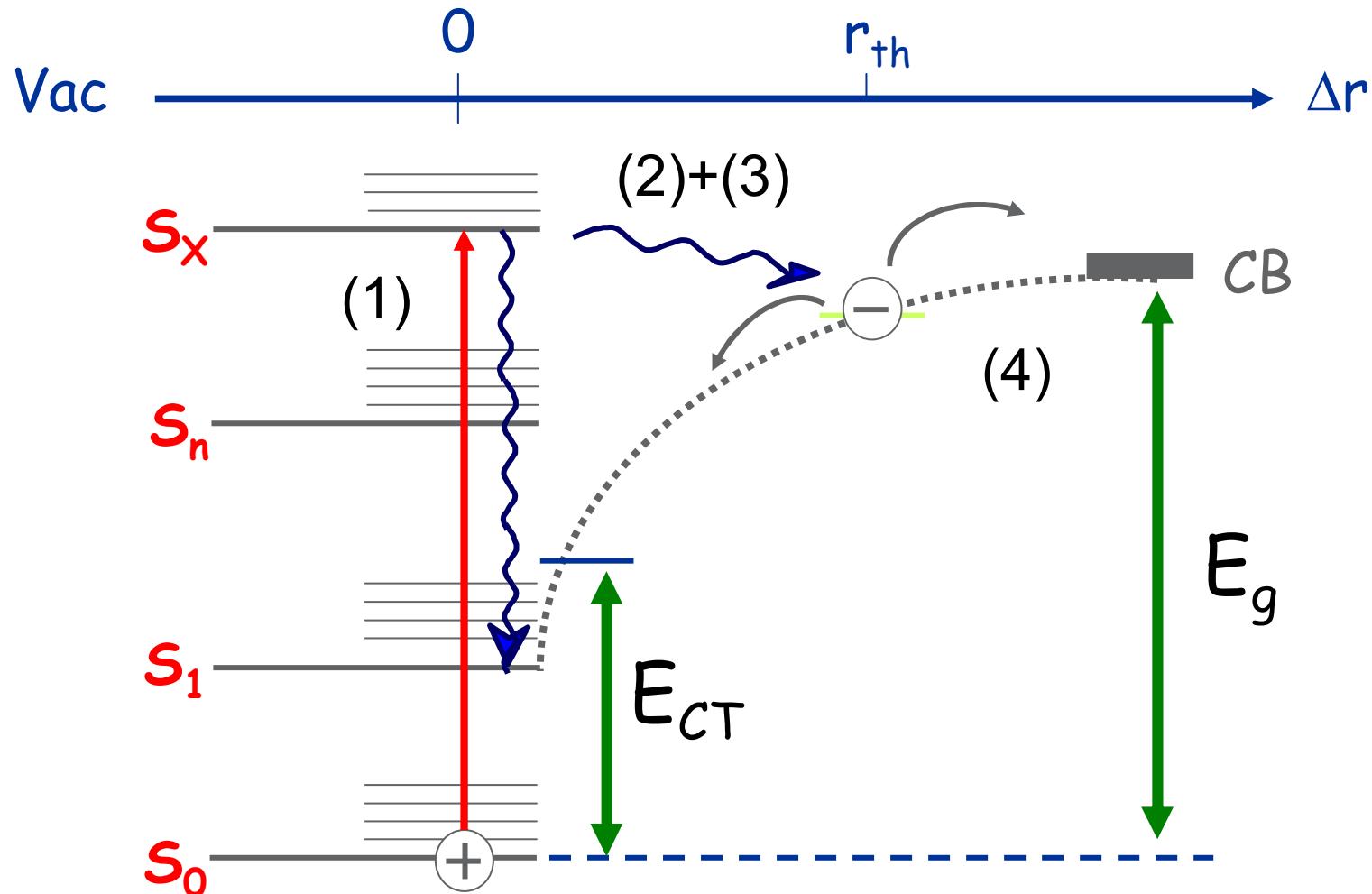
Localized state
Amorphous, Organic

$$\eta = \Phi_0 \Omega \ll 1$$

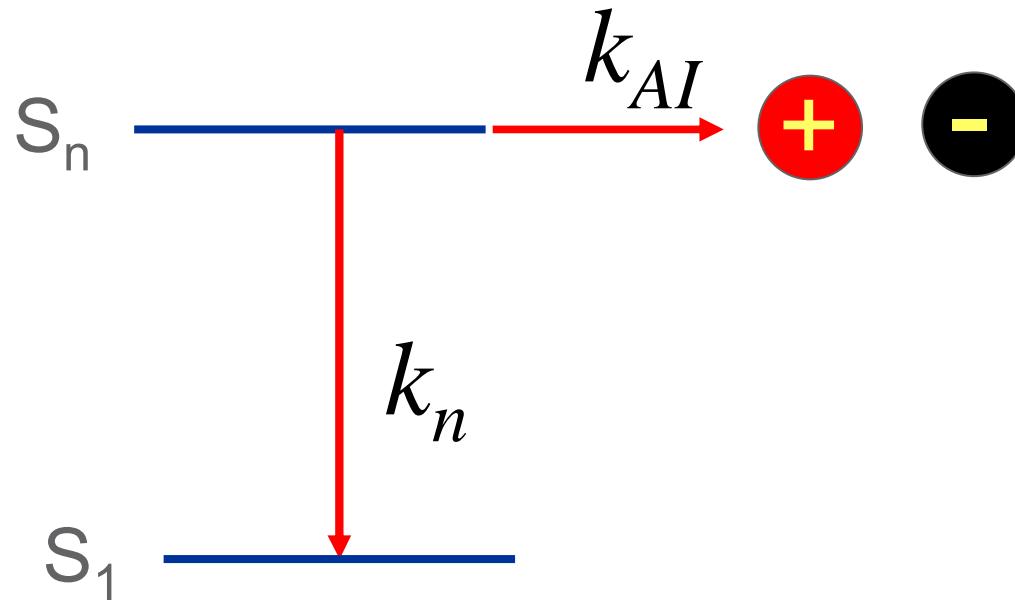


The multi-step process:

(1) Abs \rightarrow (2) AI \rightarrow (3) Thermalization \rightarrow (4) Dissociation



Auto Ionization



Inorganic Amorphous Semicond $\Phi_0=1$

Organic Semicond $\Phi_0 \ll 1$

$$\Phi_0 = \frac{k_{AI}}{k_{AI} + k_n}$$

Critical Parameters

$$\Delta E = h\nu - E_{CT}$$

Excess energy

$$r_{th} = \sqrt{D\tau_{th}}$$

Thermalization distance

$$\tau_{th} \cong \frac{\Delta E}{h\nu_p^2} \quad \longrightarrow \quad r_{th} \cong \frac{D \cdot \Delta E}{h\nu_p^2}$$

Activation Energy:

$$E_A = \frac{e^2}{4\pi\epsilon r_{th}}$$

Coulomb radius:

$$r_C = \frac{e^2}{4\pi\epsilon K T}$$

ONSAGER model

Random Walk under mutual Coulomb attraction and External field

$$\frac{\partial n(\bar{r}, t)}{\partial t} = \frac{kT}{e} \mu \nabla \cdot (e^{-U/KT} \nabla (n e^{U/KT}))$$

$$U(r) = -\frac{e}{4\pi\epsilon r} - eEr \cos\vartheta$$

n = density of diffusing particles

Boundary condition: $r=0$ is a sink (RECOMBINATION)

$n(r, 0) = g(r_{th})$ *Initial condition*

3D ONSAGER solution $\eta = \Phi_0 \Omega$

$$\Omega^{3D} = e^{-r/r_{th}} \left[1 + \frac{e}{KT} \frac{r_c E}{2!} + \dots \right]$$

Ω =escape probability

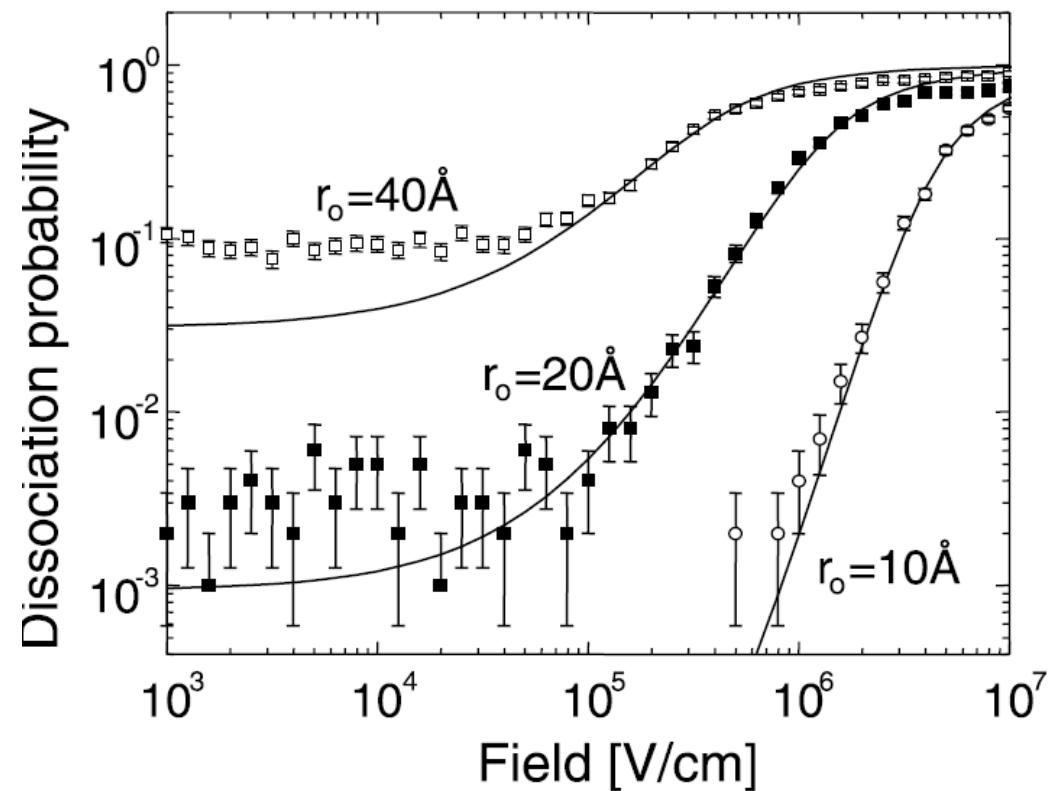
Weak Field:

$$\Omega^{3D} = A(T) e^{-r/r_{th}} \approx \Omega_0$$

Strong Field:

$$\Omega^{3D} \propto E \xrightarrow[E \rightarrow \infty]{} 1$$

Chemical Physics Letters 398 (2004) 27–31



Onsager behavior

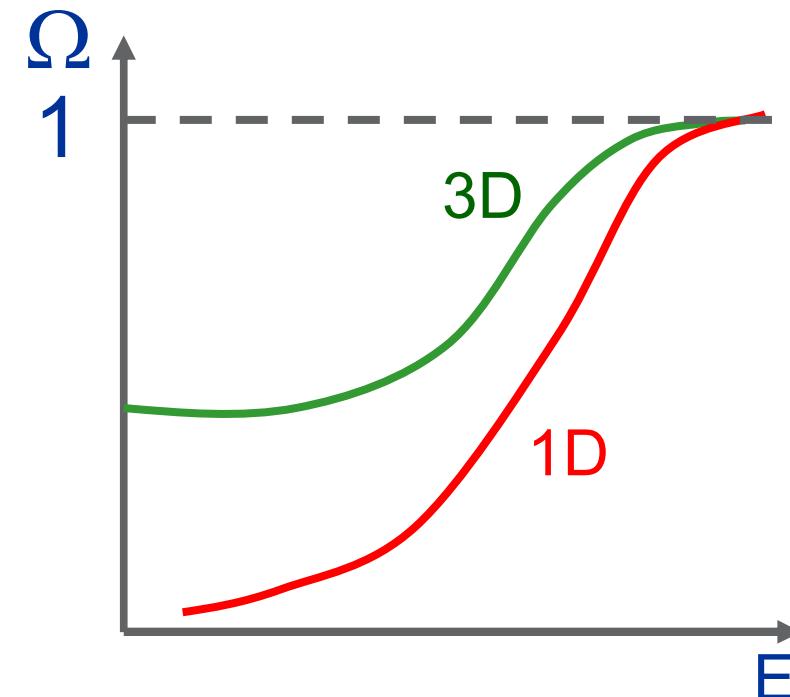
$r_{th} = r_{th}(h\nu)$:

$$r_{th} < r_C \quad \Omega^{3D} = \Omega^{3D}(F)$$

$$r_{th} > r_C \quad \Omega^{3D} \sim 1$$

Dimensionality

$$\Omega^{1D} = \frac{er_{th}^2 E}{r_C K T} e^{-r/r_{th}} \propto E$$



Poole-Frenkel model

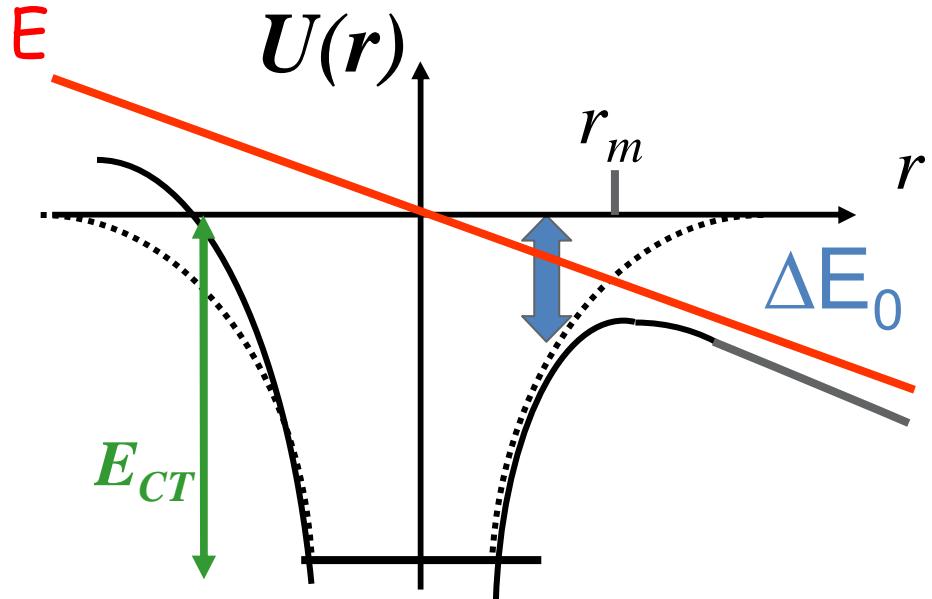
Thermal activation above Coulomb barrier

$$r_m = \sqrt{\frac{e}{\varepsilon E}}$$

$$\Delta E_0 = \sqrt{\frac{e^3 E}{\pi \varepsilon}}$$

$$E_b = E_{CT} - \Delta E_0 = E_{CT} - \beta F^{1/2}$$

$$K_{PF} = \nu \exp\left(-\frac{E_{CT}}{KT}\right) \exp\left(\frac{\beta F^{1/2}}{KT}\right)$$



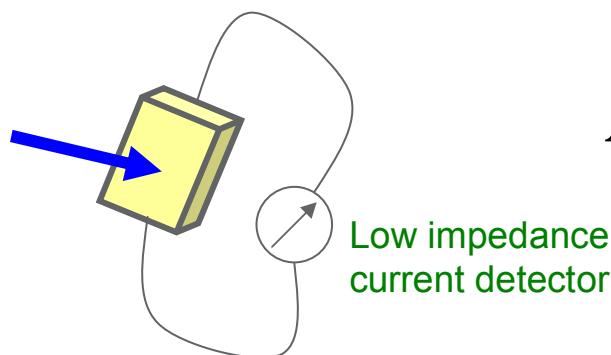
$$\Omega_{PF} = \frac{K_{PF}}{K_{PF} + K_{GPR}}$$

How to measure $\eta(E, T, h\nu)$

1) Photoconductivity

$$I_{PC} = A\Phi_0\Omega E$$

Photon Fluence



$$A = ew\mu\tau I_\nu \left(1 - e^{-\alpha(\nu)D}\right)$$

Electrode width

mobility

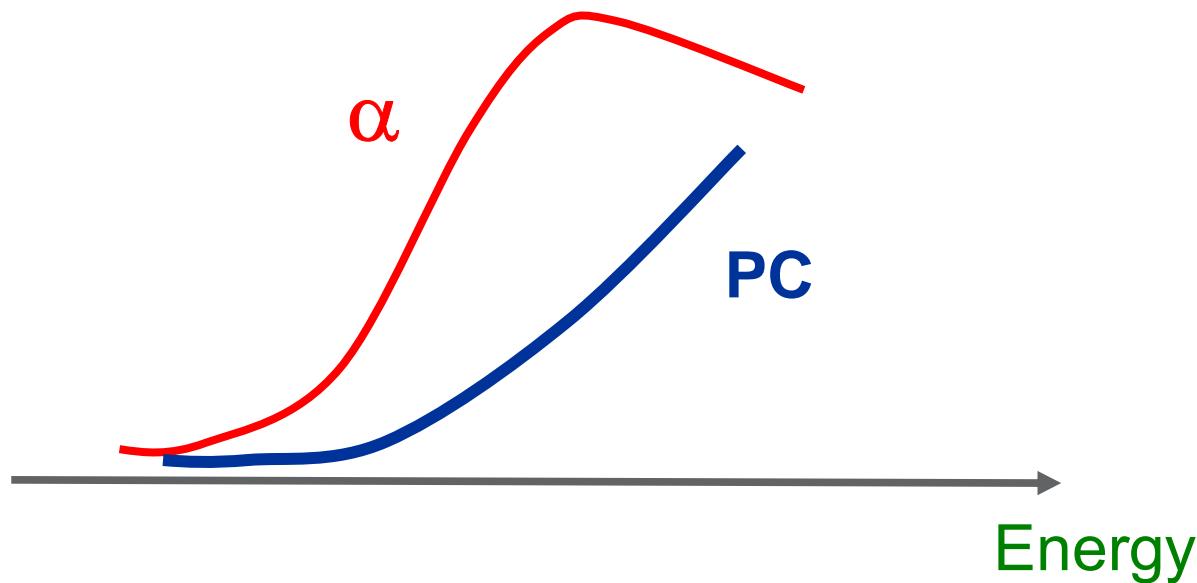
Carrier lifetime

2) Pump-probe

3) m-wave/THz

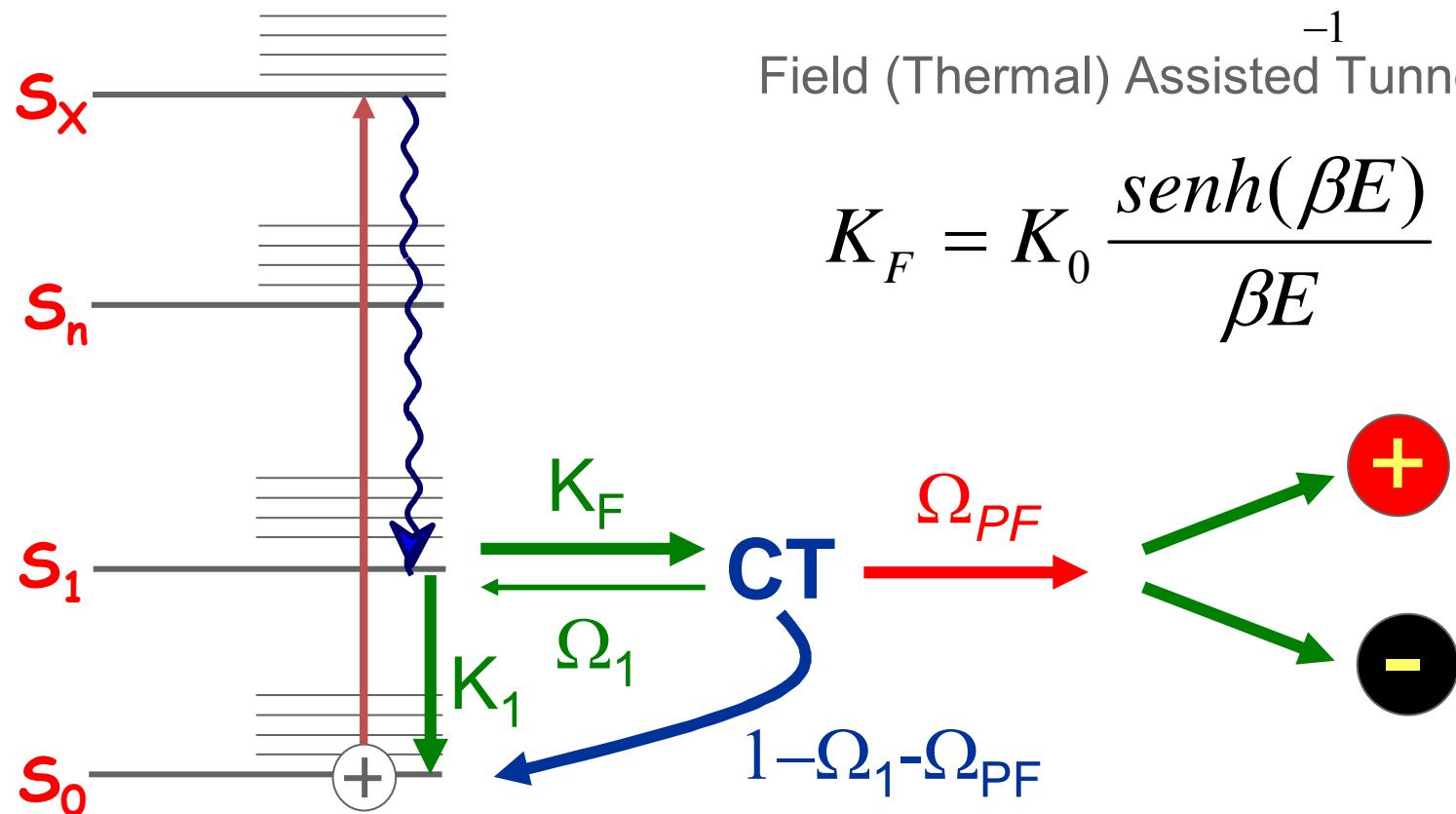
4) Field assisted PL quenching

Action spectra



In organics the optical gap and the electrical gap are different

Organic Photoconductors: when $\alpha(\omega)=PC(\omega)$



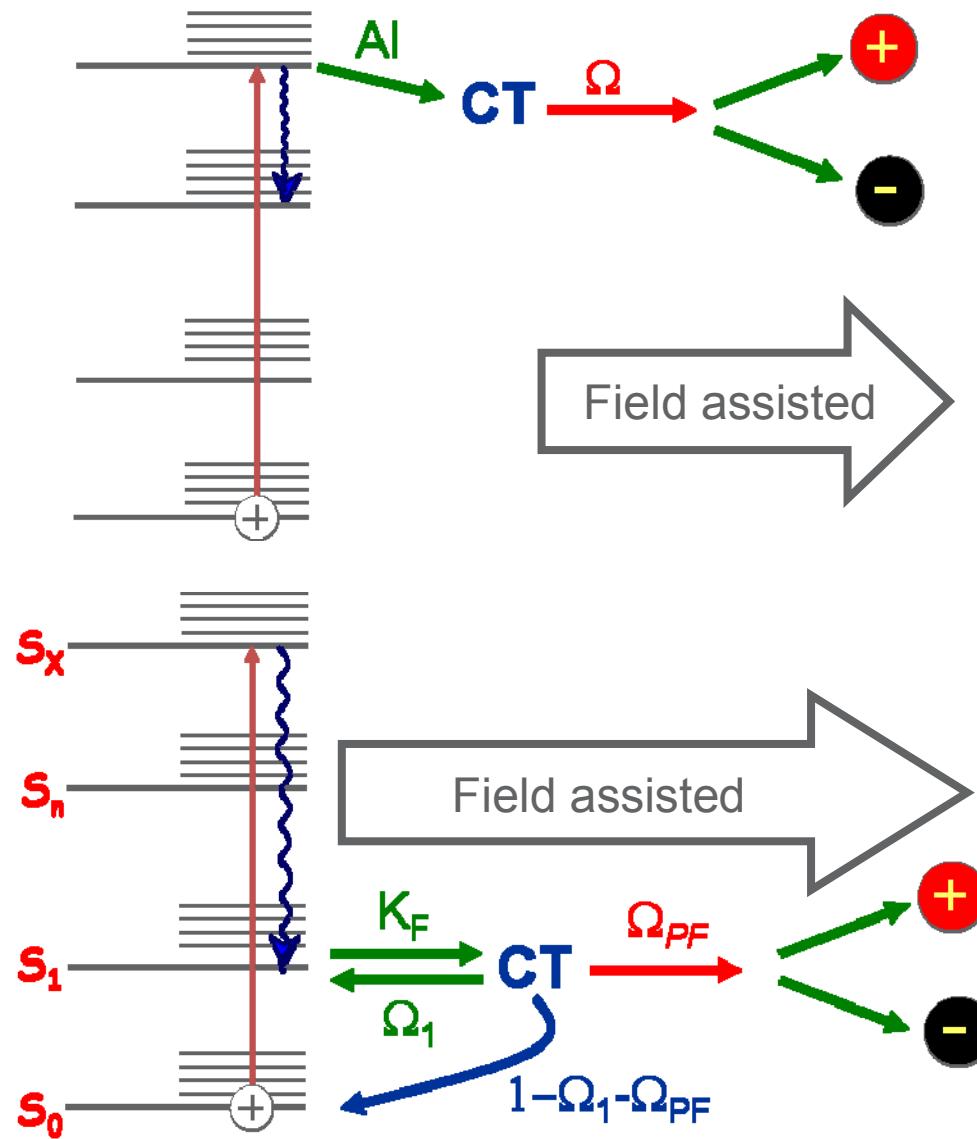
$$K_F = \frac{1}{2} K_O \int K_F^\theta d\Omega_\theta = \frac{1}{2} K_O \int e^{\beta E \cos \theta} d(\cos \theta)$$

Field (Thermal) Assisted Tunneling

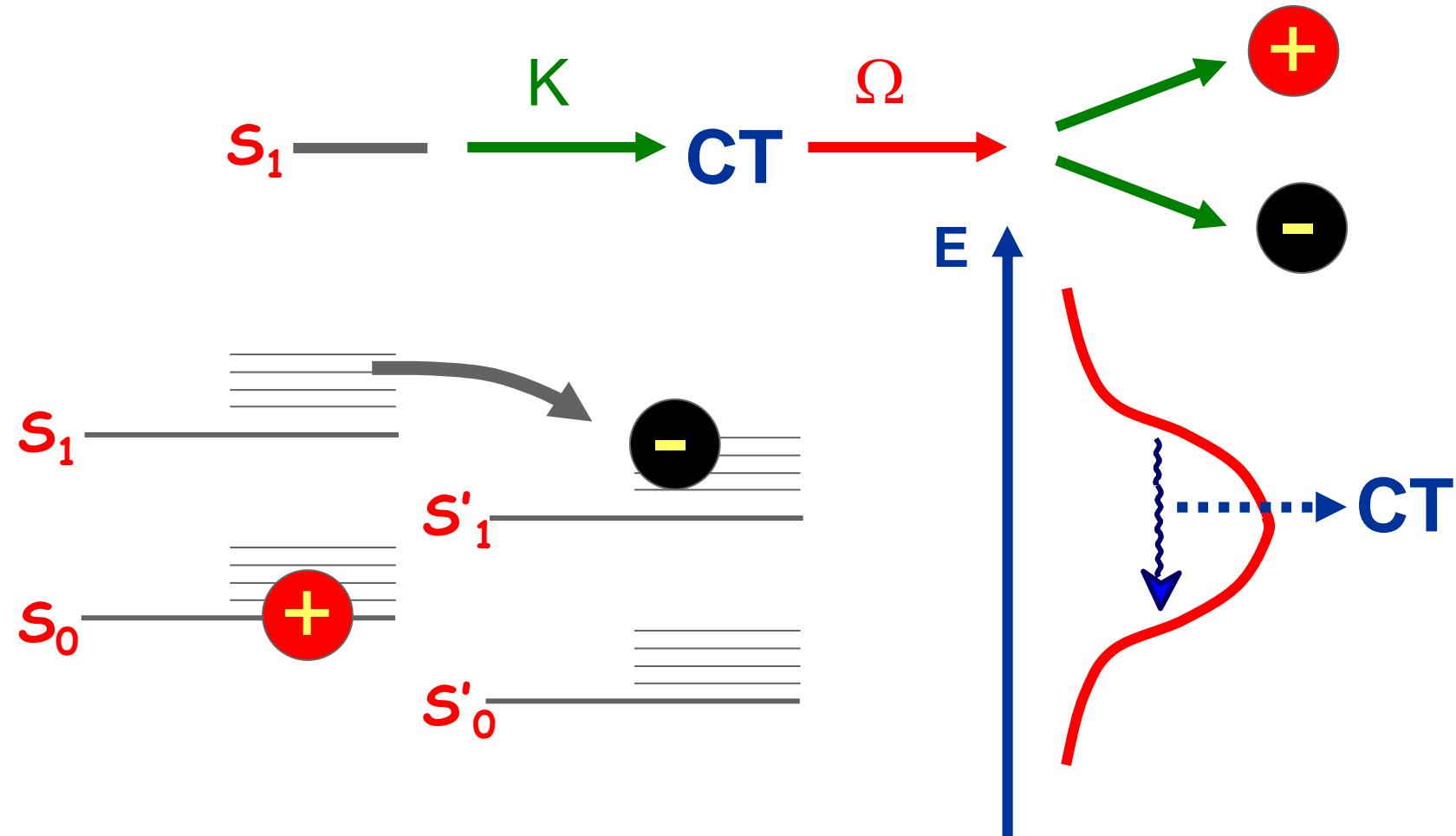
$$K_F = K_0 \frac{\operatorname{senh}(\beta E)}{\beta E}$$

Z.D. Popovic Chem. Phys. 86, 311(1984)

Comparison

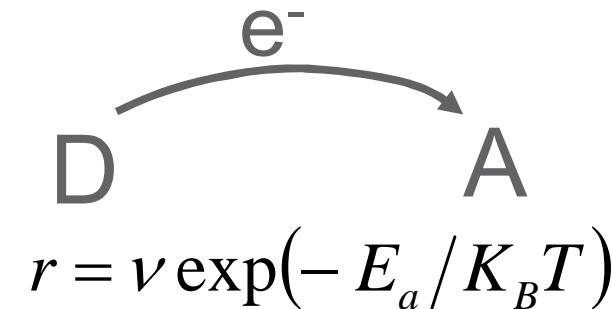


Zero Field?



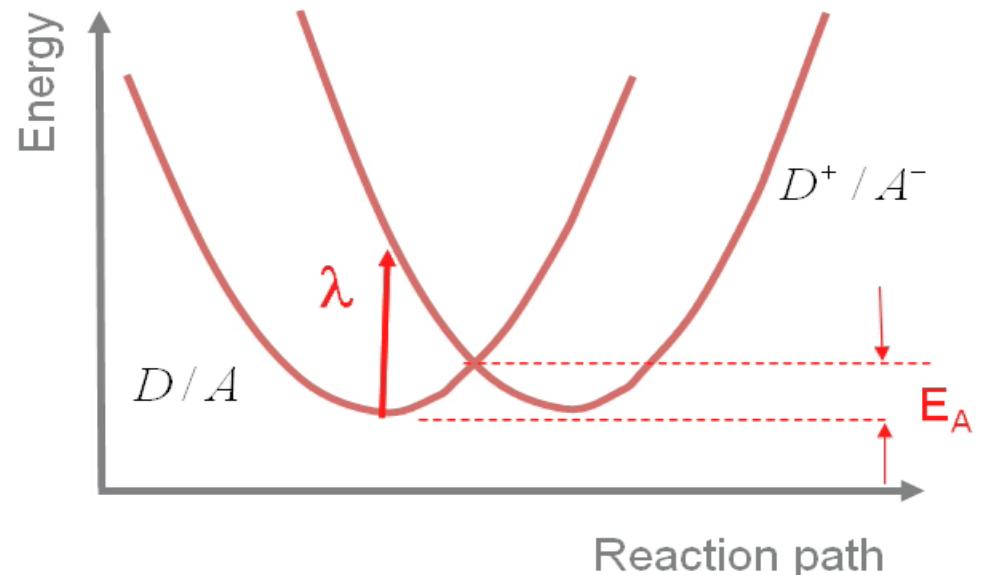
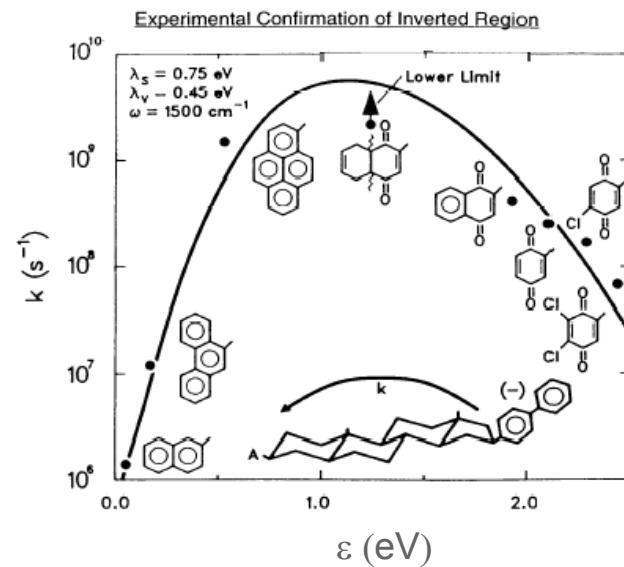
Disorder induced charge separation (H. Baessler)

The Marcus model



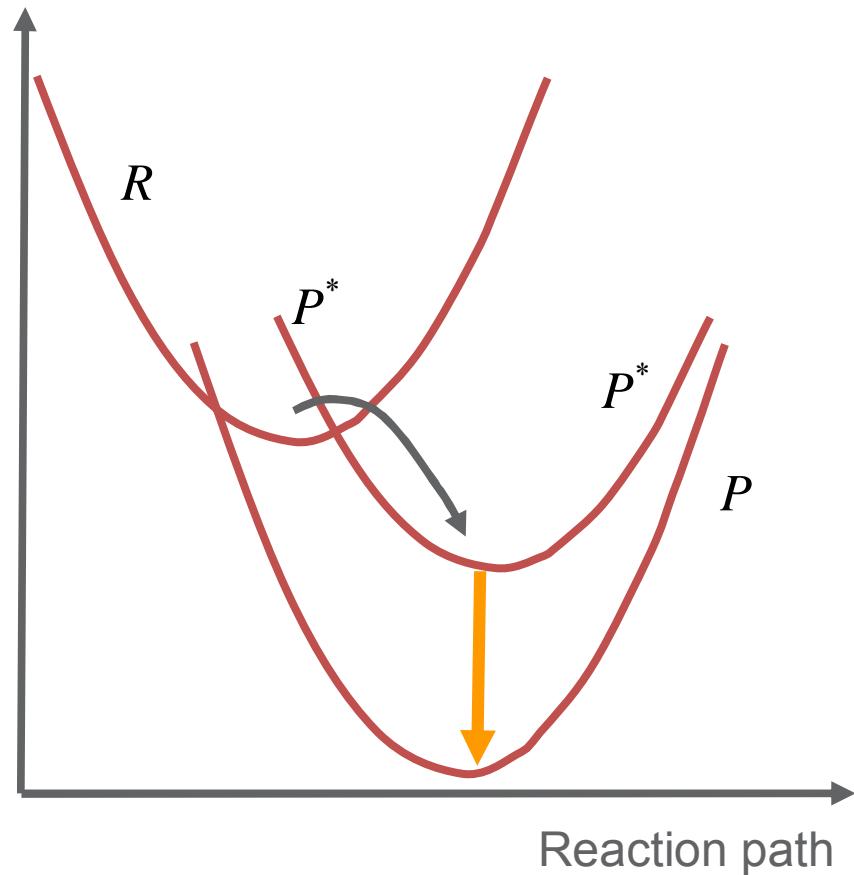
$\lambda \equiv$ Reorganization Energy

$$E_a = \frac{(\varepsilon - \lambda)^2}{4\lambda}$$



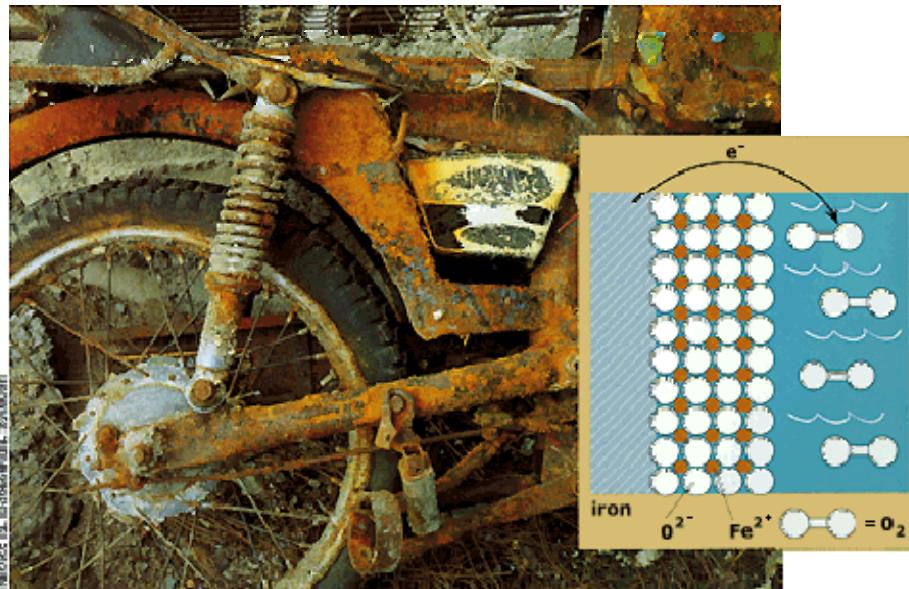
movie

A bright evidence for the inverted region



The phenomenon is an example of chemiluminescence. Safety lights of this kind, which are non-flammable and waterproof are used by seamen and divers in emergency.

Examples of Charge Transfer reactions



*To be
continued.....*